# N onm onotonic critical tem perature in superconductor/ferrom agnet bilayers

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The critical tem perature  $T_c$  of a superconductor/ferrom agnet (SF) bilayer can exhibit nonmonotonic dependence on the thickness  $d_f$  of the F layer. SF system s have been studied for a long time; according to the experimental situation, the \dirty" limit is offen considered which implies that the mean free path in the layers is the second smallest spatial scale after the Ferm i wavelength. However, all calculations reported for the dirty limit were done with some additional assumptions, which can be violated in actual experiments. Therefore, we develop a general method (to be exact, two independent methods) for investigating  $T_c$  as a function of the bilayer's parameters in the dirty case. C om paring our theory with experiment, we obtain good agreement. In the general case, we observe three characteristic types of  $T_c$  ( $d_f$ ) behavior: 1) nonmonotonic decay of  $T_c$  to a nite value exhibiting a minimum at particular  $d_f$ , 2) reentrant behavior, characterized by vanishing of  $T_c$  in a certain interval of  $d_f$  and nite values otherwise, 3) monotonic decay of  $T_c$  and vanishing at nite  $d_f$ . Q ualitatively, the nonmonotonic behavior of  $T_c$  ( $d_f$ ) is explained by the interference of quasiparticles in the F layer, which can be either constructive or destructive depending on the value of  $d_f$ .

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#### I. IN TRODUCTION

Superconductivity and ferrom agnetism are two com peting orders: while the form er \prefers" an antiparallel spin orientation of electrons in Cooper pairs, the latter forces the spins to align in parallel. Therefore, their coexistence in one and the same material is possible only in a narrow interval of param eters; hence the interplay between superconductivity and ferrom agnetism is most conveniently studied when the two interactions are spatially separated. In this case the coexistence of the two orders is due to the proximity e ect. Recently, much attention has been paid to properties of hybrid proxin ity systems containing superconductors (S) and ferrom agnets (F); new physical phenom ena were observed and predicted in these system s.<sup>1,2,3,4,5,6</sup> O ne of the most striking e ects in SF layered structures is highly nonmonotonic dependence of their critical temperature T<sub>c</sub> on the thickness df of the ferrom agnetic layers. Experim ents exploring this nonm onotonic behavior were perform ed previously on SF multilayers such as Nb/Gd<sup>7</sup>,  $Nb/Fe^{8}_{r} V/V - Fe^{9}_{r}$  and  $Pb/Fe^{10}_{r}$  but the results (and, in particular, the com parison between the experim ents and theories) were not conclusive.

To perform reliable experimental measurements of  $T_c(d_f)$ , it is essential to have  $d_f$  large compared to the interatom ic distance; this situation can be achieved only in the limit of weak ferrom agnets. A ctive experimental investigations of SF bilayers and multilayers based on Cu-Nidilute ferrom agnetic alloys are carried out by several groups.<sup>11,12</sup> In SF bilayers, they observed nonmonotonic dependence  $T_c(d_f)$ . While the reason for this e ect in multilayers can be the O{ transition, <sup>3</sup> in a bilayer system with a single superconductor this mechanism is irrelevant, and the cause of the e ect is interference of

quasiparticle, speci c to SF structures.

In the present paper, motivated by the experim ents of Refs. 11,12 we theoretically study the critical tem perature of SF bilayers. Previous theoretical investigations of T<sub>c</sub> in SF structures were concentrated on systems with thin or thick layers (com pared to the corresponding coherence lengths); with SF boundaries having very low or very high transparencies; the exchange energy was often assumed to be much larger than the critical temperature; in addition, the methods for solving the problem were usually approximate.<sup>3,4,9,10,13,14,15,16</sup> The parameters of the experim ents of R efs. 11,12 do not correspond to any of the above limiting cases. In the present paper we develop two approaches giving the opportunity to investigate not only the lim iting cases of param eters but also the interm ediate region. U sing our m ethods, we nd di erent types of nonm onotonic behavior of T<sub>c</sub> as a function of df, such as m in im um of Tc and even reentrant superconductivity. C om parison of our theoretical predictions with the experim ental data shows good agreem ent.

A number of methods can be used for calculating  $T_{\rm c}$ . When the critical temperature of the structure is close to the critical temperature  $T_{\rm cs}$  of the superconductor without the ferror agnetic layer, the G inzburg (Landau (GL) theory applies. However,  $T_{\rm c}$  of SF bilayers may significantly deviate from  $T_{\rm cs}$ , therefore we choose a more general theory valid at arbitrary temperature | the quasiclassical approach  $^{17,18,19}$  Near  $T_{\rm c}$  the quasiclassical approach  $^{17,18,19}$  Near  $T_{\rm c}$  the quasiclassical approach  $^{14,14,15,16}$  which is argued to be qualitatively reasonable in a wide region of parameters. However, this method is justile only in a speci c region of parameters which we nd below . Moreover, below we show examples when this method fails even qualitatively reasonable with the set of the set

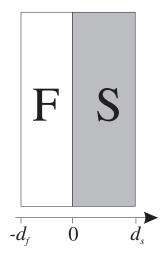


FIG.1: SF bilayer. The F and S layers occupy the regions  $d_f < x < 0$  and  $0 < x < d_s$ , respectively.

itatively. Thus there is need for an exact solution of the linearized quasiclassical equations. The limiting case of perfect boundaries and large exchange energy was treated by R adovic et al.<sup>3</sup>

Based on the progress achieved for calculation of  $T_c$  in SN systems (where N denotes a nonmagnetic normal material),<sup>20</sup> we develop a generalization of the singlemode approximation | the multimode method. Although this method seems to be exact, it is suble to justify it rigorously. Therefore we develop yet another approach (this time mathematically rigorous), which we call \the method of fundamental solution". The models considered previously<sup>3,4,9,10,13,14,15,16</sup> correspond to limiting cases of our theory. A part of our results was brie y reported in Ref. 21.

The paper is organized as follows. In Sec. II we form ulate the U sadel equations and the corresponding boundary conditions. Section III is devoted to the exact multim ode method for solving the general equations. An alternative exact method, the method of fundamental solution, is presented in Sec. IV. In Sec. V we describe results of our methods. In Sec. V I, a qualitative explanation of our results is presented, applicability of the results to multilayered structures is discussed, and the use of a com plex di usion constant is commented upon. C onclusions are presented in Sec. V II. A ppendixes A, B contain analytical results for limiting cases. Finally, technical details of the calculations are given in Appendix C.

### II. M O D E L

We assume that the dirty-lim it conditions are fulled, and calculate the critical tem perature of the bilayer within the fram ework of the linearized U sadelequations for the S and F layers (the domain  $0 < x < d_s$  is occupied by the S m etal,  $d_{\rm f} < x < 0$  | by the F m etal, see Fig. 1). Near T<sub>c</sub> the norm alG reen function is

 $G = \mbox{sgn} \mid_n$  , and the U sadel equations for the anom abus function F take the form

$$\int_{s}^{2} T_{cs} \frac{d^{2} F_{s}}{dx^{2}} \qquad j!_{n} F_{s} + = 0; \quad 0 < x < d_{s}; \quad (1)$$

$$\int_{f}^{2} T_{cs} \frac{d^{2} F_{f}}{dx^{2}} \qquad (j!_{n} j+ iE_{ex} sgn !_{n}) F_{f} = 0; \qquad (2)$$

$$d_{f} < x < 0;$$

$$\ln \frac{T_{cs}}{T} = T \frac{X}{j!_n j} F_s$$
(3)

(the pairing potential is nonzero only in the S part). Here  $_{\rm S} = {}^{\rm D} {}_{\rm S}=2 {\rm T}_{\rm cs}$ ,  $_{\rm f} = {}^{\rm D} {}_{\rm D} {}_{\rm f}=2 {\rm T}_{\rm cs}$  are the coherence lengths, while the di usion constants can be expressed via the Ferm i velocity and the mean free path: D = vl=3; !\_n = T (2n + 1) with n = 0; 1; 2;::: are the M atsubara frequencies; E  $_{\rm ex}$  is the exchange energy; and T  $_{\rm cs}$  is the critical tem perature of the S m aterial. F  $_{\rm S(f)}$  denotes the function F in the S(F) region. We use the system of units in which P lanck's and B oltzm ann's constants equal unity, ~ = k\_{\rm B} = 1.

Equations (1) { (3) must be supplemented with the boundary conditions at the outer surfaces of the bilayer:

$$\frac{\mathrm{dF}_{\mathrm{s}}(\mathrm{d}_{\mathrm{s}})}{\mathrm{dx}} = \frac{\mathrm{dF}_{\mathrm{f}}(\mathrm{d}_{\mathrm{f}})}{\mathrm{dx}} = 0; \qquad (4)$$

as well as at the SF boundary :22

s

$$\frac{\mathrm{dF}_{\mathrm{s}}(0)}{\mathrm{dx}} = \int_{\mathrm{f}} \frac{\mathrm{dF}_{\mathrm{f}}(0)}{\mathrm{dx}}; \qquad \qquad = \frac{\mathrm{s}}{\mathrm{f}} \int_{\mathrm{f}} (5)$$

$$_{f b} \frac{dF_{f}(0)}{dx} = F_{s}(0) \quad F_{f}(0); \quad b = \frac{R_{b}A}{f f}:$$
 (6)

Here  $_{s, f}$  are the norm al-state resistivities of the S and F m etals,  $R_b$  is the resistance of the SF boundary, and A is its area. The U sadel equation in the F layer is readily solved:

$$F_{f} = C (!_{n}) \cosh (k_{f} [x + d_{f}]);$$
(7)  
$$k_{f} = \frac{1}{f} \frac{j!_{n} j + iE_{ex} sgn !_{n}}{T_{cs}};$$

and the boundary condition at x = 0 can be written in closed form with respect to  $F_{\rm s}$  :

$${}_{s}\frac{dF_{s}(0)}{dx} = \frac{1}{b + B_{f}(!_{n})}F_{s}(0); \qquad (8)$$
$$B_{f} = [k_{f} + tanh(k_{f}d_{f})]^{-1}:$$

This boundary condition is complex. In order to rewrite it in a real form, we do the usual trick and go over to the functions

$$F = F(!_n) F(!_n)$$
: (9)

A coording to the U sadel equations (1){(3), there is the symmetry  $F(!_n) = F(!_n)$  which implies that  $F^+$  is realwhile F is a purely in aginary function.

The symmetric properties of F  $^+$  and F  $\,$  with respect to  $!_n$  are trivial, so we shall treat only positive  $!_n$ . The self-consistency equation is expressed only via the symmetric function  $F_s^+$ :

$$\ln \frac{T_{cs}}{T} = T \frac{X}{!_{n} > 0} \frac{2}{!_{n}} F_{s}^{+}; \qquad (10)$$

and the problem of determining  $T_{\rm c}$  can be formulated in a closed form with respect to  $F_{\rm s}^+$  as follows. The U sadel equation for the antisymmetric function  $F_{\rm s}^-$  does not contain , hence it can be solved analytically. A fler that we exclude  $F_{\rm s}^-$  from boundary condition (8) and arrive at the elective boundary conditions for  $F_{\rm s}^+$ :

$${}_{s}\frac{dF_{s}^{+}(0)}{dx} = W (!_{n})F_{s}^{+}(0); \qquad \frac{dF_{s}^{+}(d_{s})}{dx} = 0; \quad (11)$$

where

$$W (!_{n}) = \frac{A_{s}(_{b} + ReB_{f}) +}{A_{s}j_{b} + B_{f}j + (_{b} + ReB_{f})};$$
(12)  
$$A_{s} = k_{s} tanh(k_{s}d_{s}); \quad k_{s} = \frac{1}{s} \frac{r}{T_{cs}}:$$

The self-consistency equation (10) and boundary conditions (11){(12), together with the U sadel equation for  $F_{\rm s}^{\;+}$ :

$${}_{s}^{2} T_{cs} \frac{d^{2} F_{s}^{+}}{dx^{2}} \qquad !_{n} F_{s}^{+} + 2 = 0$$
(13)

will be used below for nding the critical tem perature of the bilayer.

The problem can be solved analytically only in  $\lim$ iting cases (see Appendix A). In the general case, one should use a numerical method, and below we propose two methods for solving the problem exactly.

# III. MULTI-MODE METHOD

# A. Starting point: the single-m ode approxim ation and its applicability

In the single-m ode approximation (SM A) one seeks the solution of the problem (10) { (13) in the form

$$F_{s}^{+}(x;!_{n}) = f(!_{n}) \cos \frac{x d_{s}}{s}$$
; (14)

$$(\mathbf{x}) = \cos \frac{\mathbf{x} \quad \mathbf{d}_{s}}{s} \quad : \qquad (15)$$

This anzatz automatically satis es boundary condition (11) at  $x = d_s$ .

The Usadel equation (13) yields

$$f(!_{n}) = \frac{2}{!_{n} + {}^{2} T_{cs}};$$
 (16)

then the self-consistency Eq. (10) takes the form ( and do not depend on !  $_{\rm n})$ 

$$\ln \frac{T_{cs}}{T_c} = \frac{1}{2} + \frac{2}{2} \frac{T_{cs}}{T_c} = \frac{1}{2} ; \quad (17)$$

where is the digam m a function.

Boundary condition (11) at x = 0 yields

$$\tan \quad \frac{d_s}{s} = W \quad (!_n): \quad (18)$$

The critical temperature  $T_c$  is determined by Eqs. (17),(18).

A lthough thism ethod is popular, it is often used without pointing out the lim its of its applicability. We present the explicit formulation of the corresponding condition: the single-mode method is correct only if the parameters are such that W can be considered  $!_n$ -independent [because the left-hand side of Eq. (18) must be  $!_n$ independent].<sup>13</sup>

Appendix B dem on strates examples of the SM A validity and corresponding analytical results.

In one of experim entally relevant cases,  $E_{ex} = T_{cs} > 1$ ,  $d_f$ , the SMA is applicable if  $E_{ex} = T_{cs}$  1 = b(see Appendix B for details).

# B. Inclusion of other modes

The single-m ode approximation implies that one takes the (only) real root of Eq. (17). An exact (multimode) method for solving problem (10) { (13) is obtained if we also take imaginary roots into account | there is in nite number of these.<sup>20</sup>

Thus we seek the solution in the form

$$F_{s}^{+}(x; !_{n}) = f_{0}(!_{n}) \cos \qquad_{0} \frac{x \quad d_{s}}{s} + \int_{m=1}^{M} f_{m}(!_{n}) \frac{\cosh \qquad_{m} \frac{x \quad d_{s}}{s}}{\cosh \qquad_{m} \frac{d_{s}}{s}}; (19)$$

$$(\mathbf{x}) = {}_{0} \cos {}_{0} \frac{\mathbf{x} \quad \mathbf{d}_{s}}{s} + \frac{\mathbf{x}^{d}}{m = 1} m \frac{\cosh m \frac{\mathbf{x} \quad \mathbf{d}_{s}}{s}}{\cosh m \frac{\mathbf{d}_{s}}{s}}; \qquad (20)$$

(The norm alizing denom inators in the  $\cosh$ -term s have been introduced in order to increase accuracy of num erical calculations.) This anzatz autom atically satis es boundary condition (11) at  $x = d_s$ .

Substituting the anzatz  $\mathbb{E}$  qs. (19){(20)] into the Usadel equation (13), we obtain

$$f_{0}(!_{n}) = \frac{2_{0}}{!_{n} + \frac{2}{0} T_{cs}};$$

$$f_{m}(!_{n}) = \frac{2_{m}}{!_{n} - \frac{2}{m} T_{cs}}; \quad m = 1;2;:::;$$
(21)

then the parameters are determined by the self-consistency equation (10) ( and do not depend on  $!_n$ ):

$$\ln \frac{T_{cs}}{T_c} = \frac{1}{2} + \frac{\frac{2}{0}}{2} \frac{T_{cs}}{T_c} = \frac{1}{2} ; \qquad (22)$$

$$\ln \frac{T_{cs}}{T_c} = \frac{1}{2} \frac{\frac{2}{m}}{2} \frac{T_{cs}}{T_c} \frac{1}{2} ; m = 1;2; \dots$$

From Eqs. (22) and properties of the digam m a function<sup>23</sup> it follows that the parameters belong to the following intervals:

$$0 < \frac{2}{0} < \frac{1}{2_{F}};$$
 (23)

$$\frac{T_{c}}{T_{cs}} (2m \qquad 1) < \frac{2}{m} < \frac{T_{c}}{T_{cs}} (2m + 1); \quad m = 1; 2; \dots;$$

where  $_{\rm E}$  1:78 is Euler's constant.

Boundary condition (11) at x = 0 yields the following equation for the amplitudes :

The critical temperature  $T_c$  is determined by Eqs. (22) and the condition that Eq. (24) has a nontrivial (!  $_n$  - independent) solution with respect to .

N um erically, we take a nite num ber of modes: m = 0;1;:::;M . To take account of  $!_n$ -independence of the solution, we write down Eq. (24) at the M atsubara frequencies up to the N th frequency: n = 0;1;:::;N . Thus we arrive at the matrix equation K nm m = 0 with the following matrix  $\hat{K}$ :

$$K_{n0} = \frac{W(!_{n})\cos(0_{ds} = s) - 0 \sin(0_{ds} = s)}{!_{n} = T_{cs} + \frac{2}{0}};$$

$$K_{nm} = \frac{W(!_{n}) + m \tanh(0_{m} = s)}{!_{n} = T_{cs} - \frac{2}{m}};$$

$$n = 0;1;...;N; m = 1;2;...;M:$$

W = take M = N, then the condition that Eq. (24) has a nontrivial solution takes the form

$$\det \hat{K} = 0: \tag{26}$$

Thus the critical tem perature  $T_c$  is determ ined as the largest solution of Eqs. (22),(26).

# IV. METHOD OF FUNDAMENTAL SOLUTION

By de nition, the fundamental solution  $G(x;y;!_n)$  (which is also called the G reen function) of problem (11){

(13) satis es the same equations, but with the delta-functional <code>\source":</code>

$${}_{s}^{2} T_{cs} \frac{d^{2}G(x;y)}{dx^{2}} \quad !_{n}G(x;y) = (x \quad y); \quad (27)$$

$$_{\rm s} \frac{{\rm dG} (0; y)}{{\rm dx}} = W (!_{\rm n}) G (0; y); \qquad \frac{{\rm dG} ({\rm d}_{\rm s}; y)}{{\rm dx}} = 0:$$
 (28)

The fundam ental solution can be expressed via solutions  $v_1$ ,  $v_2$  of Eq. (27) without the delta-function, satisfying the boundary conditions at x = 0 and  $x = d_s$ , respectively:

$$G (x;y;!_{n}) = \frac{k_{s}=!_{n}}{\sinh(k_{s}d_{s}) + (W = k_{s} \cdot s)\cosh(k_{s}d_{s})}$$
$$v_{1}(x)v_{2}(y); \quad x \in y$$
$$v_{2}(x)v_{1}(y); \quad y \in x;$$
(29)

. .

where

$$v_1 (x) = \cosh (k_s x) + (W = k_{s s}) \sinh (k_s x);$$
 (30a)  
 $v_2 (x) = \cosh (k_s [x d_s]):$  (30b)

Having found G (x;y;  $!_n$ ), we can write the solution of Eqs. (11) { (13) as

$$F_{s}^{+}(x;!_{n}) = 2 G(x;y;!_{n}) (y)dy:$$
(31)

Substituting this into the self-consistency equation (10), we obtain

(x) 
$$\ln \frac{T_{cs}}{T_c}$$
  
= 2  $T_c$   
 $\frac{X}{!_n > 0}$   $\frac{(x)}{!_n}$   $Z_{d_s}$   $(x;y;!_n)$   $(y)dy$  : (32)

This equation can be expressed in an operator form:  $\ln (T_{cs}=T_c) = \hat{L}$ . Then the condition that Eq. (32) has a nontrivial solution with respect to is expressed by the equation

det 
$$\hat{L}$$
  $\hat{l} \ln \frac{T_{cs}}{T_c} = 0$ : (33)

The critical tem perature  $T_{\rm c}$  is determ ined as the largest solution of this equation.

Numerically, we put problem (32),(33) on a spatial grid, so that the linear operator  $\hat{L}$  becomes a nite matrix.

# V. NUMERICAL RESULTS

In Secs. III, IV we developed two methods for calculating the critical temperature of a SF bilayer. Specifying parameters of the bilayer we can do the critical temperature numerically. It can be checked that the

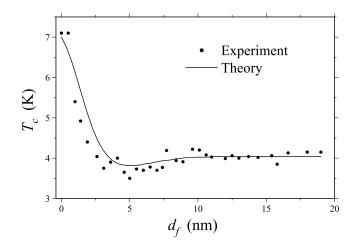


FIG.2: Theoretical tto the experim entaldata of Ref.11. In the experim ent, N b was the superconductor (with  $d_{\rm s}=11\,{\rm nm}$ ,  $T_{\rm cs}=7\,{\rm K}$ ) and C  $u_{0:43}N$   $i_{0:57}$  was the weak ferrom agnet. From our two estimate E $_{\rm ex}=130\,{\rm K}$  and  $_{\rm b}=0.3$ .

m ultim ode m ethod and the m ethod of fundam ental solution yield equivalent results. However, at sm all tem peratures  $T_c$   $T_{cs}$ , the calculation time for the m ultim ode m ethod increases. Indeed, the size of the m atrix  $\hat{K}$  [Eq. (25)] is determ ined by the number N of the m axim um M atsubara frequency  $!_N$ , which m ust be m uch larger than the characteristic energy  $T_{cs}$ ; hence N  $T_{cs}=T_c$ . Therefore, at low tem peratures we use the m ethod of fundam ental solution.

### A. Comparison with experiment

Using our methods we t the experimental data of Ref. 11; the result is presented in Fig. 2. Estimating the parameters  $d_s = 11 \text{ nm}$ ,  $T_{cs} = 7 \text{ K}$ ,  $_s = 7.5 \text{ cm}$ ,  $_s = 8.9 \text{ nm}$ ,  $_f = 60 \text{ cm}$ ,  $_f = 7.6 \text{ nm}$ , = 0.15 from the experiment,<sup>25</sup> and thing only E ex and b, we nd good agreement between our theoretical predictions and the experimental data.

The tting procedure was the following: rst, we determ in E  $_{\rm ex}$  130K from the position of them in in um of T  $_{\rm c}$  (d  $_{\rm f}$ ); second, we nd  $_{\rm b}$  0:3 from tting the vertical position of the curve.

The deviation of our curve from the experimental points is small; it is most pronounced in the region of smalld<sub>f</sub> corresponding to the initial decrease of  $T_c$ . This is not unexpected because, when  $d_f$  is of the order of a few nanom eters, the thickness of the F lm may vary signic cantly along the lm (which is not taken into account in our theory), and the thinnest lm s can even be form ed by an array of islands rather than by continuous material. At the same time, we emphasize that the minimum of  $T_c$  takes place at  $d_f$  5 nm, when with good accuracy the F layer has uniform thickness.

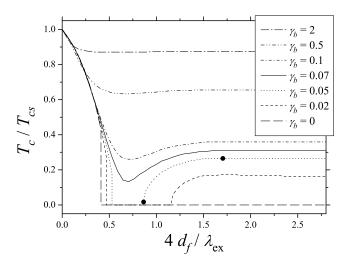


FIG.3: Characteristic types of  $T_c$  (d<sub>f</sub>) behavior. The thickness of the F layer is measured in units of the wavelength ex de ned in Eq. (40). The curves correspond to di erent values of b. The exchange energy is  $E_{ex} = 150 \text{ K}$ ; the other parameters are the same as in Fig. 2. One can distinguish three characteristic types of  $T_c$  (d<sub>f</sub>) behavior: 1) nonmonotonic decay to a nite  $T_c$  with a minimum at particular d<sub>f</sub> ( $_b = 2; 0.5; 0.1; 0.07$ ), 2) reentrant behavior ( $_b = 0.05; 0.02$ ), 3) monotonic decay to  $T_c = 0$  at nite d<sub>f</sub> ( $_b = 0$ ). The bold points indicate the choice of parameter corresponding to Fig. 6.

### B. Various types of $T_{\rm c}\,(d_{\rm f}\,)$ behavior

The experimental results discussed above represent only one possible type of  $T_{\rm c}$  (df) behavior. Now we address the general case; we obtain dierent kinds of  $T_{\rm c}$  (df) curves depending on parameters of the bilayer.

To illustrate, in Fig.3 we plot several curves for various values of  $_{\rm b}$  [we recall that  $_{\rm b}$  / R $_{\rm b}$ , where R $_{\rm b}$  is the resistance of the SF interface in the norm all state | see Eq. (6)]. The exchange energy is  $E_{\rm ex} = 150$  K; the other parameters are the same as in Fig.2.

We observe three characteristic types of  $T_c (d_f)$  behavior: 1) at large enough interface resistance,  $T_c$  decays nonmonotonically to a nite value exhibiting a minimum at a particular  $d_f$ , 2) at moderate interface resistance,  $T_c$  demonstrates the reentrant behavior: it vanishes in a certain interval of  $d_f$ , and is nite otherwise, 3) at low enough interface resistance,  $T_c$  decaysm onotonically vanishing at nite  $d_f$ . A sim ilar succession of  $T_c (d_f)$  curves as in F ig.3 can be obtained by tuning other parameters, e.g., the exchange energy  $E_{ex}$  or the norm al resistances of the layers (the parameter ).

A common feature seen from Fig. 3 is saturation of  $T_c$  at large  $d_f$  & ex. This fact has a simple physical explanation: the suppression of superconductivity by a dirty ferrom agnet is only due to the elective F layer with thickness on the order of ex, adjacent to the interface (this is the layer explored and \felt" by quasiparticles entering from the S side due to the proximity elect).

It was shown by Radovic et al.<sup>3</sup> that the order of

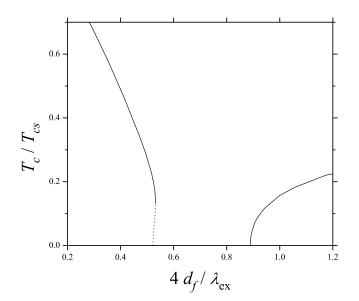


FIG. 4: Change of the phase transition's order. This phenom enon manifests itself as discontinuity of  $T_c$  ( $d_f$ ): the critical tem perature jumps to zero abruptly without taking intermediate values. Form ally,  $T_c$  becomes a double-valued function, but the smaller solution is physically unstable (dotted curve). For illustration we have chosen the curve from Fig. 3 corresponding to  $_b = 0.05$ .

the phase transition may change in short-periodic SF superlattices, becoming the rst order. We also observe this feature in the curves of types 2) and 3) mentioned above. This phenom enon manifests itself as discontinuity of  $T_c$  ( $d_f$ ): the critical temperature jumps to zero abruptly without taking intermediate values (see Figs. 3,4). Form ally,  $T_c$  becomes a double-valued function, but the sm aller solution is physically unstable (dotted curve in Fig. 4).

A n interesting problem is determ ination of the tricritical point where the order of the phase transition changes. The corresponding result for hom ogeneous bulk superconductors with internal exchange eld was obtained a long time ago in the fram ework of the G inzburg{Landau theory.<sup>26</sup> However, the generalization to the case when the GL theory is not valid is a subtle problem which has not yet been solved. We note that the equations used in R efs. 3,15 were applied beyond their applicability range because they are GL results valid only when  $T_c$  is close to  $T_{cs}$ .

# ${\tt C}$ . Comparison between single-and multimode $${\tt m$}$$ ethods

A popular method widely used in the literature for calculating the critical temperature of SF bi- and multilayers is the single-mode approximation. The condition of its validity was formulated in Sec. IIIA. How ever, this approximation is often used for arbitrary system's pa-

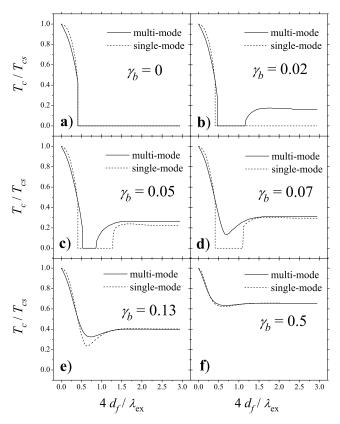


FIG.5: C om parison between single- and multimode methods. The parameters are the same as in Fig.3. Generally speaking, the results of the single-mode and multimode (exact) methods are quantitatively and even qualitatively different: b), c), d), and e). However, sometimes the results are close: a) and f). Thus the single-mode approximation can be used for quick estimates, but reliable results should be obtained by one of the exact (multimode or fundamentalsolution) techniques.

ram eters. U sing the m ethods developed in Secs. III, IV, we can check the actual accuracy of the single-m ode approxim ation. The results are presented in Fig. 5.

W e conclude that although at som e param eters the results of the single-m ode and multim ode (exact) m ethods are close (Figs. 5 a,f), in the general case they are quantitatively and even qualitatively di erent [Figs. 5 b,c,d,e | these cases correspond to the m ost nontrivial  $T_c$  (d<sub>f</sub>) behavior]. Thus to obtain reliable results one should use one of the exact (multim ode or fundam ental-solution) techniques.

### D. Spatial dependence of the order param eter

The proxim ity e ect in the SF bilayer is characterized by the spatial behavior or the order parameter, which can be chosen as

$$F(x; = 0) = T F(x;!_n);$$
 (34)

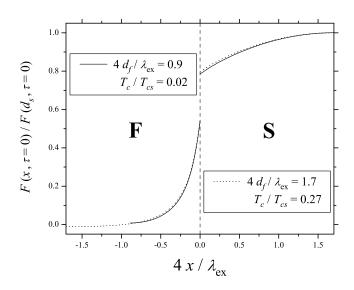


FIG.6: Spatial dependence of the order parameter norm alized by its value at the outer surface of the S layer. Two cases are shown di ering by the thickness of the F layer d<sub>f</sub> (and by the corresponding T<sub>c</sub>) at  $_{\rm b}$  = 0.05. The other parameters are the same as in Fig. 3, where the chosen cases are indicated by the bold points. A lthough the critical tem peratures di er by m ore than the order of m agnitude, the norm alized order parameters are very close to each other, which m eans that the value of T<sub>c</sub> has alm ost no e ect on the shape of F (x; = 0). The jum p at the SF interface is due to its nite resistance. W ith an increase of d<sub>f</sub> the order parameter starts to oscillate, changing its sign (this can be seen for the dotted curve, although negative values of the order parameter have very sm all am plitudes).

where denotes the imaginary time [in the S metal F (x; = 0) / (x)]. This function is real due to the symmetry relation F ( $!_n$ ) = F ( $!_n$ ).

W e illustrate this dependence in F ig. 6, which shows two cases di ering by the thickness of the F layer d<sub>f</sub> (and by the corresponding  $T_c$ ). A libough the critical tem peratures di er by m ore than the order of m agnitude, the norm alized order parameters are very close to each other, which m eans that the value of  $T_c$  has alm ost no e ect on the shape of F (x; = 0). D etails of the calculation are presented in Appendix C.

A nother feature seen from F ig. 6 is that the order param eter in the F layer changes its sign when the thickness of the F layer increases (this feature can be seen for the dotted curve, although negative values of the order param eter have very sm all am plitudes). We discuss this oscillating behavior in the next section.

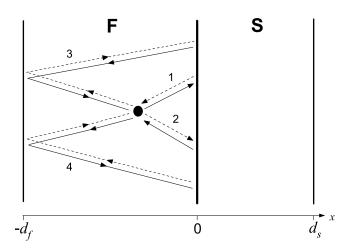


FIG.7: Four types of trajectories contributing (in the sense of Feynm an's path integral) to the anom alous wave function of correlated quasiparticles in the ferrom agnetic region. The solid lines correspond to electrons, the dashed lines | to holes; the arrows indicate the direction of the velocity.

### VI. DISCUSSION

# A . Qualitative explanation of the nonm onotonic $T_{\rm c}\left(d_{\rm f}\right) \, \text{behavior}$

The thickness of the F layer at which the minimum of  $T_{\rm c}\,(d_{\rm f}\,)$  occurs, can be estimated from qualitative arguments based on the interference of quasiparticles in the ferrom agnet.

Let us consider a point x inside the F layer. A coording to Feynm an's interpretation of quantum mechanics,  $r^{27}$ the quasiparticle wave function may be represented as a sum of wave am plitudes over all classical trajectories; the wave am plitude for a given trajectory is equal to exp (iS), where S is the classical action along this trajectory. We are interested in an anom abus wave function of correlated quasiparticles, which characterizes superconductivity; this function is equivalent to the anom alous G reen function F (x). To obtain this wave function we must sum over trajectories that (i) start and end at the point x, (ii) change the type of the quasiparticle (i.e., convert an electron into a hole, or vice versa). There are four kinds of trajectories that should be taken into account (see Fig. 7). Two of them (denoted 1 and 2) start in the direction toward the SF interface (as an electron and as a hole), experience the Andreev re ection, and return to the point x. The other two trajectories (denoted 3 and 4) start in the direction away from the interface, experience norm alre ection at the outer surface of the F layer, m ove toward the SF interface, experience the Andreev re ection there, and nally return to the point x. The main contribution is given by the trajectories normal to

the interface. The corresponding actions are

$$S_1 = Q x ; \qquad (35)$$

$$S_2 = Q x ; \qquad (36)$$

$$S_3 = Q (2d_f + x)$$
; (37)

$$S_4 = Q (2d_f + x)$$
 (38)

(note that x < 0), where Q is the di erence between the wave numbers of the electron and the hole, and

=  $\arccos(E = )$  is the phase of the Andreev re ection. To make our arguments more clear, we assume that the ferrom agnet is strong, the SF interface is ideal, and consider the clean  $\lim_{x \to \infty} \frac{\operatorname{int} \operatorname{int} \operatorname{rst:} \operatorname{then} Q = k_e \quad k_h = 2\operatorname{m} (E + E_{ex} + ) \quad 2\operatorname{m} (E - E_{ex} + ) \quad 2E_{ex} = v$ , where E is the quasiparticle energy, is the Ferm i energy, and v is the Ferm i velocity. Thus the anom alous wave function of the quasiparticles is

F (x) / 
$$\sum_{n=1}^{X^4} \exp(iS_n) / \cos(Q d_f) \cos(Q (d_f + x))$$
: (39)

The suppression of  $T_{\rm c}$  by the ferrom agnet is determ ined by the value of the wave function at the SF interface: F (0) /  $\cos^2$  (Q d\_f). The minimum of  $T_{\rm c}$  corresponds to the minimum value of F (0) which is achieved at  $d_{\rm f}$  = =2Q. In the dirty limit the above expression for Q is replaced by

$$Q = \frac{E_{ex}}{D_{f}} \frac{2}{e_{x}}$$
(40)

(here we have de ned the wavelength of the oscillations  $e_x$ ); hence the minimum of  $T_c$  (d<sub>f</sub>) takes place at

$$d_{f}^{(m \text{ in})} = \frac{r}{2} \frac{D_{f}}{E_{ex}} = \frac{ex}{4}$$
: (41)

For the bilayer of Ref. 11 we obtain  $d_f^{(m in)}$  7 nm, whereas the experimental value is 5 nm (Fig. 2); thus our qualitative estimate is reasonable.

The arguments given above seem to yield not only the minimum but rather a succession of minima and maxima. However, numerically we obtain either a single minimum or a minimum followed by a weak maximum (Fig. 3). The reason for this is that actually the anomalous wave function not only oscillates in the ferrom agnetic layer but also decays exponentially, which makes the amplitude of the subsequent oscillations almost invisible.

Finally, we note that our arguments concerning oscillations of F (x) also apply to a half-in nite ferror agnet, where we should take into account only the trajectories 1 and 2 (see Fig. 7). This yields F (x) /  $\cos(Q x)$  (another qualitative explanation of this result can be found, for example, in Ref. 14).

### B. Multilayered structures

The methods developed and the results obtained in this paper apply directly to more complicated symmetricm ultilayered structures in the 0-state such as SFS and FSF trilayers, SFIFS and FSISF system s (Idenotes an arbitrary potential barrier), and SF superlattices. In such system s an SF bilayer can be considered as a unit cell, and joining together the solutions of the U sadel equations in each bilayer we obtain the solution for the whole system (form ore details see Sec. V III of R ef. 28).

O urm ethods can be generalized to take account of possible superconductive and/orm agnetic states (when and/or  $E_{ex}$  m ay change their signs from layer to layer). In this case the system cannot be equivalently separated into a set of bilayers. M athem atically, this m eans that the solutions of the U sadel equations lose their purely cosine form [see Eqs. (7), (14), (15), (19), (20), (30b)] acquiring a sine part as well.

### C. Com plex di usion constant?

Finally, we comment on Refs. 4,15,16,29, where the authors considered (in the vicinity of T<sub>c</sub>) di usion equations with a complex di usion constant D<sub>f</sub> for the F part of the structure. This im plies sm all com plex corrections 1 in the U sadel equations ( is the to D  $_{\rm f}$  over E  $_{\rm ex}$ time of the mean free path). However, we disagree with this method for the following reason: although the com plex D<sub>f</sub> can indeed be form ally obtained in the course of the standard derivation of the U sadel equations<sup>17</sup> from the Eilenberger ones<sup>30</sup> by expanding over the spherical harm onics, one can check that the higher harm onics neglected in the derivation have the same order of magnitude as the retained complex correction to D<sub>f</sub>. Hence the complexity of D<sub>f</sub> in the context of the U sadel equations is the excess of accuracy. Below we present our argum ents.

We give a brief derivation of the U sadel equations showing how the complex di usion constant can be obtained and why this result cannot be trusted. In the \quasi-one-dimensional" geometry (which means that the parameters vary only as a function of x) the linearized E ilenberger equation in the presence of disorder and the exchange eld has the form

$$\frac{v\cos}{2}\frac{d}{dx}F + !_{n} + \frac{1}{2} + iE_{ex}F = + \frac{hFi}{2}; \quad (42)$$

where, for simplicity, we assume a positive M atsubara frequency  $!_n > 0$ , and is the angle between the x axis and the direction of the Ferm i velocity v, while h:::i denotes angular averaging over the spherical angles. The disorder is characterized by the time of the m ean free path and the m ean free path 1 (to be used below). In the dirty lim it the anom alous G reen function F is nearly isotropic. How ever, to obtain the U sadel equation for the isotropic part of F, we must also take into account the

next term from the full Legendre polynom ial expansion:

$$F(x;!_{n};) = \begin{cases} X^{k} \\ F_{k}(x;!_{n})P_{k}(\cos) \\ \\ F_{0}(x;!_{n}) + F_{1}(x;!_{n})\cos : \end{cases}$$
(43)

Here we have neglected the harm onics with k > 2 assum - ing them sm all; we shall check this assumption later.

A veraging Eq. (42) over the spherical angles rst directly and second  $\left| \begin{array}{c} \mbox{after being multiplied by } \cos$  , we arrive at

$$\frac{v}{6}\frac{d}{dx}F_{1} + (!_{n} + iE_{ex})F_{0} = ; \qquad (44)$$

$$\frac{v}{2}\frac{d}{dx}F_0 + !_n + \frac{1}{2} + iE_{ex} F_1 = 0:$$
 (45)

Equation (45) yields

$$F_{1} = \frac{1}{1 + 2!_{n} + 2iE_{ex}} \frac{d}{dx}F_{0}; \quad (46)$$

then Eq. (44) leads to

$$\frac{D}{2} \frac{d^2}{dx^2} F_0 \qquad (!_n + iE_{ex}) F_0 + = 0; \qquad (47)$$
vl=3

$$D = \frac{1+2!_{p}+2iE_{ex}}{1+2!_{p}+2iE_{ex}}$$

Now we must check that the assumption  $F_1=F_0 j = 1$ ,  $F_2=F_1 j = 1$ , etc. that we used is indeed satistical. From Eq. (46) we obtain

$$\frac{F_1}{F_0} = \frac{I=L}{\max(1;2!_n;2E_{ex})}; \quad (48)$$

where L is the characteristic space scale on which F  $_{\rm 0}$  varies. According to the U sadel equation (47), it is given by

L 
$$\frac{1}{\max(1;2!_{n};2E_{ex})\max(2!_{n};2E_{ex})};$$
 (49)

and the condition of the Usadel equation's validity is written as

$$\frac{F_1}{F_0} = \frac{\max(2!_n; 2E_{ex})}{\max(1; 2!_n; 2E_{ex})} = 1$$
(50)

[sim ilarly, we can also keep the term with k = 2 in series (43), which yields  $f_2=F_1j$   $f_1=F_0j$  etc.].

Finally, condition (50) takes the form

$$2 T_{cs} 1; 2E_{ex} 1$$
 (51)

(we have taken into account that the characteristic energy is  $!_n T_{cs}$ ).

Now we can analyze our results. If condition (51) is satis ed and the U sadel equation is valid, the neglected angular harm onics have the relative order of m agnitude  $f_2=F_0j$  max(2 T<sub>cs</sub>; 2E<sub>ex</sub>); hence we cannot retain the term s of the same order in the di usion constant [see Eq. (47)], and we should use the standard expression D = vl=3.

## VII. CONCLUSIONS

In the present paper we have developed two m ethods for calculating the critical tem perature of a SF bilayer as a function of its param eters (the thicknesses and m aterial param eters of the layers, the quality of the interface). The multimode m ethod is a generalization of the corresponding approach developed in Ref. 20 for SN systems. However, the rigorous justication of this m ethod is not clear. Therefore, we propose yet another approach leveloped in the method of fundam ental solution, which is m athem atically rigorous. The results demonstrate that the two m ethods are equivalent; how ever, at low tem peratures (com pared to  $T_{\rm cs}$ ) the accuracy requirem ents are stricter for the multimode m ethod, and the m ethod of fundam mental solution is preferable. Com paring our m ethod with experiment we obtain good agreem ent.

In the general case, we observe three characteristic types of  $T_c (d_f)$  behavior: 1) nonmonotonic decay of  $T_c$  to a nite value exhibiting a minimum at particular  $d_f$ , 2) reentrant behavior, characterized by vanishing of  $T_c$  in a certain interval of  $d_f$  and nite values otherwise, 3) monotonic decay of  $T_c$  and vanishing at nite  $d_f$ . Qualitatively, the nonmonotonic behavior of  $T_c (d_f)$  is explained by interference of quasiparticles in the F layer, which can be either constructive or destructive depending on the value of  $d_f$ .

U sing the developed m ethods we have checked the accuracy of the widely used single-m ode approxim ation. We conclude that although at some parameters the results of the single-m ode and exact m ethods are close, in the general case they are quantitatively and even qualitatively di erent. Thus, to obtain reliable results one should use one of the exact (m ultim ode or fundam entalsolution) techniques.

The spatial dependence of the order parameter (at the transition point) is shown to be almost insensitive to the value of  $T_c$ .

The methods developed and the results obtained in this paper apply directly to more complicated symmetric multilayered structures in the 0-state such as SFS and FSF trilayers, SFIFS and FSISF systems, and SF superlattices. Our methods can be generalized to take account of possible superconductive and/or magnetic - states (when and/or E  $_{\rm ex}$  may change their signs from layer to layer).

W e argue that the use of the com plex di usion constant in the U sadel equation is the excess of accuracy.

In several lim iting cases, T<sub>c</sub> is considered analytically.

### A cknow ledgm ents

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# APPENDIX A: ANALYTICAL RESULTS FOR A THIN S LAYER

(i) When  $d_s = a$  and  $E_{ex} = T_{cs}$ , problem (10){ (13) can be solved analytically. The rst of the above conditions in plies that can be considered constant, and  $F^+$  weakly depends on the spatial coordinate; so  $F^+(x;!_n) = 2 = !_n + A(!_n) \cosh(k_s[x d_s])$ . The boundary conditions determ ine the coe cient A; as a result

$$F^{+}(!_{n}) = \frac{2}{!_{n}} \frac{A_{s}(!_{n})}{A_{s}(!_{n}) + W(!_{n})};$$
(A1)

where  $k_{\rm s}, A_{\rm s},$  and W are de ned in Eq. (12). Finally, the self-consistency equation for  $T_{\rm c}$  takes the form

$$\ln \frac{T_{cs}}{T_c} = Re \qquad \frac{1}{2} + \frac{1}{2} \frac{s}{d_s} \frac{1}{b} + B_f \frac{T_{cs}}{T_c} \qquad \frac{1}{2} ;$$
(A2)

where  $B_f$  does not depend on  $!_n$  due to the condition  $E_{ex} = T_{cs}$ :

$$B_{f} = [k_{f f} \tanh (k_{f} d_{f})]^{-1}; \qquad k_{f} = \frac{1}{f} \frac{iE_{ex}}{T_{cs}}: (A3)$$

(ii) If the F layer is also thin,  $d_f = \frac{p_{D_f}}{D_f} = 2E_{ex}$ , Eq. (A2) is further simplified:

$$\ln \frac{T_{cs}}{T_c} = Re \qquad \frac{1}{2} + \frac{f}{s} \qquad \frac{1}{1 + fE_{ex}} \qquad \frac{E_{ex}}{2 T_c} \qquad \frac{1}{2};$$
(A 4)

where  $_{s, f}$  are de ned similarly to Ref. 28:

$$_{s} = \frac{2d_{s}R_{b}A}{_{s}D_{s}}; \qquad f = \frac{2d_{f}R_{b}A}{_{f}D_{f}}; \qquad (A 5)$$

and have the physical meaning of the escape time from the corresponding layer. They are related to the quantities ,  $_{\rm b}$  used in the body of the paper as

$$_{s} = -\frac{b}{T_{cs}} \frac{1}{s} \frac{d_{s}}{s}; \qquad f = -\frac{1}{b} \frac{d_{f}}{T_{cs}} \frac{d_{f}}{f}: \quad (A 6)$$

(iii) If the S layer is thin,  $d_s = s$ , and the SF interface is opaque,  $b \leq 1$ , the critical tem perature of the bilayer

only slightly deviates from  $T_{cs}$ . In this lim it Eq. (A1) applies with  $W = = {}_{b} 1$ , and we nally obtain:

$$T_{c} = T_{cs} \quad \frac{1}{4s} : \qquad (A7)$$

Interestingly, characteristics of the F layer (d<sub>f</sub>,  $E_{ex}$ , etc.) do not enter the form ula. In particular, this form ula is valid for an SN bilayer<sup>31,32</sup> (where N is a nonmagnetic norm al material,  $E_{ex} = 0$ ) because Eq. (A 7) was obtained without any assumptions about the value of the exchange energy.

### 1. Transparent interface

When both layers are very thin  $[d_s] = \frac{p}{D_s=2!_p}$ ,  $d_f = min(D_f=2!_p; D_f=2E_{ex})$ , with  $!_p$  the Debye energy of the S m etal] and the interface is transparent, the bilayer is equivalent to a hom ogeneous superconducting layer with internal exchange eld. This layer is described by e ective parameters: the pairing potential  $(e^{-})$ , the exchange eld  $E_{ex}^{-(e^{-})}$ , and the pairing constant  $(e^{-})$ . In this subsection we develop the ideas of R ef. 33, dem onstrate a sim ple derivation of this description, and nd the limits of its applicability.

The U sadel equations (1),(2) for the two layers can be written as a single equation:

$$\frac{D_{f}(x) + D_{s}(x)}{2} \frac{d^{2}F}{dx^{2}}$$

$$j!_{n} f = iE_{ex} sgn(!_{n}) (x)F + (x) = 0; \quad (A8)$$

where is the H eaviside function [ (x > 0) = 1, (x < 0) = 0]. The self-consistency equation (3) can be rew ritten as

$$(x) = (x) T F(x;!_n);$$
 (A9)

where is the pairing constant.

First, we consider the ideal SF interface:  $_{b} = 0$  [see Eq. (6)], then F (x) is continuous at the interface and nearly constant across the whole bilayer, i.e.,  $F_{s}(x) = F_{f}(x) = F$ . Applying the integral operator to Eq. (A8):

$$\frac{f}{sd_s + fd_f} \begin{bmatrix} Z \\ 0 \\ d_f \end{bmatrix} dx + \frac{s}{sd_s + fd_f} \begin{bmatrix} Z \\ d_s \end{bmatrix} dx \quad (A \ 10)$$

(here is the norm alm etal density of states), and cancelling gradient term s due to the boundary condition (5), we obtain the equations describing a hom ogeneous layer:

$$j!_n \not F (!_n) = iE_{ex}^{(e_n)} sgn(!_n)F(!_n) + (e_n) = 0;$$
  
(A 11)
  
(e\_n) = (e\_n) T ((n) + (e\_n) = 0;
  
(A 10) (A

$$(e) = (e) T F(!_n);$$
 (A 12)

with the e ective parameters (see also R ef. 33):

$$E_{ex}^{(e)} = \frac{f}{s+f} E_{ex}; \qquad {}^{(e)} = \frac{s}{s+f}; \qquad (A 13)$$
$${}^{(e)} = \frac{s}{s+f}; \qquad T_{cs}^{(e)} = \frac{-E}{2!} \exp -\frac{1}{(e)};$$

where  $_{\rm E}$  is Euler's constant and  $T_{\rm cs}^{(e)}$  is the critical tem – perature of the layer in the absence of ferrom agnetism (i.e., at  $E_{\rm ex}^{(e)} = 0$ ). The critical tem perature is determined by the equation

$$\ln \frac{T_{cs}^{(e)}}{T_{c}} = Re \quad \frac{1}{2} + i \frac{E_{ex}^{(e)}}{2 T_{c}} \quad \frac{1}{2} : \quad (A14)$$

A ctually, the description in term s of e ective parameters (A13) is applicable at an arbitrary tem perature (i.e., when the U sadel equations are nonlinear) and has a clear physical interpretation: the superconducting (, ) and ferrom agnetic (E  $_{\rm ex}$ ) parameters are renormalized according to the part of time spent by quasiparticles in the corresponding layer. This physical picture is based on interpretation of as escape times, which we present in the next subsection.

Now we discuss the applicability of the above description for a nonideal interface ( $_{\rm b}$  6 0). In this case F is nearly constant in each layer, but these constants are di erent:  $F_{\rm s}(x) = F_{\rm s} + C_{\rm s}(x - d_{\rm s})^2$ ,  $F_{\rm f}(x) = F_{\rm f} + C_{\rm f}(x + d_{\rm f})^2$ , where  $F_{\rm s}$  j  $f_{\rm s}$  j $d_{\rm s}^2$  and  $F_{\rm f}$  j  $f_{\rm c}$  j $d_{\rm f}^2$ . Using the U sadel equation (A 8) and the boundary conditions (5), (6), we not the di erence F  $F_{\rm s} = F_{\rm s}$   $F_{\rm f}$ :

$$F = \frac{1}{\frac{1}{s} + j!_{n}j + \frac{1}{f(j!_{n}j+iE_{ex} sgn!_{n})}}; \quad (A 15)$$

Finally, the homogeneous description is valid when jF = Fj = 1 [with F determined by Eq. (A11)], which yields:

$$\max(\mathbf{E}_{ex};!) \max(\mathbf{s}; f) \quad 1 \quad (A16)$$

(here  $!_n !_{_D}$  has been taken as the largest characteristic energy scale in the quasi-hom ogeneous bilayer).

### 2. Interpretation of as escape times

The quantities  $_{s, f}$  introduced in Eq. (A 5) may be interpreted as escape times from the corresponding layers. The arguments go as follows.

If the layers are thin, then the di usion inside the layers is \fast" and the escape time from a layer is determined by the interface resistance. The time of penetration through a layer or the interface is determined by the corresponding resistance:  $R_{s(f)}$  or  $R_b$ , hence the di usion is \fast" if  $R_{s(f)}$  R<sub>b</sub>.

Let us use the detailed balance approach, and consider an interval of energy dE. In the S layer, the charge in this interval is  $Q_s = e_s dE A d_s$ . Let us de ne the escape time from the S layer  $t_s$ , so that the current from S to F is equal to  $Q_s = t_s$ . On the other hand, this current can be written as  $dE = eR_b$ , hence

$$\frac{Q_{s}}{t_{s}} = \frac{dE}{eR_{b}}; \qquad (A 17)$$

and we immediately obtain

$$t_{s} = \frac{d_{s}R_{b}A}{{}_{s}D_{s}}:$$
 (A 18)

Similarly, we obtain the expression for the escape time from the F layer  $t_f$ . As a result, the relations between the quantities de ned in Eq. (A 5) and the escape times t are simply

$$_{s} = 2t_{s}; \quad f = 2t_{f}:$$
 (A19)

M icroscopic expressions for the escape times may be obtained using the Sharvin formula for the interface resistance. Assuming, for de niteness, that the Ferm i velocity is smaller in the S metal,  $v_{\rm s} < v_{\rm f}$ , we obtain

$$R_{b} = \frac{r_{b}}{e^{2} sv_{s}A};$$
 (A 20)

and consequently

$$t_{s} = \frac{d_{s}}{v_{s}}r_{b}; \qquad t_{f} = \frac{v_{f}d_{f}}{v_{s}^{2}}r_{b}; \qquad (A\,21)$$

where  $r_b$  is the inverse transparency of one channel. The asymmetry in these expressions stems from our assum ption  $v_s < v_f$ . In the opposite case the indices s and f in Eqs. (A 20), (A 21) should be interchanged.

# APPENDIX B:APPLICABILITY OF THE SINGLE-MODE APPROX IM AT ION

A spointed out in Sec. IIIA, the single-m ode approxim ation (SM A) is applicable only if the parameters are such that W [see Eq. (12)] can be considered  $!_n$ independent. An example is the case when  $_b \quad \mathcal{B}_f \mathbf{j}$ hence W = =  $_b$ .

The condition  $_{\rm b}$   $\beta_{\rm f}$  j can be written in a simpler form; to this end we should estimate  $\beta_{\rm f}$  j. We introduce the real and in aginary parts of  $k_{\rm f}$ :  $k_{\rm f} = k_{\rm f}^0 + i k_{\rm f}^0$ , and note that  $k_{\rm f}^0 > k_{\rm f}^0$ . Then using the properties of the trigonom etric functions and the estimate tanh x m in (1;x) we obtain

$$\mathcal{B}_{f} j \quad k_{f}^{0} f \tanh(k_{f}^{0} d_{f})^{-1}; \qquad (B1)$$

and nally cast the condition  $b = \beta_f j$  into the form

$$\frac{1}{b} \quad \min \quad \max \quad \frac{T_c}{T_{cs}}; \frac{E_{ex}}{T_{cs}}; \frac{d_f}{f} \max \quad \frac{T_c}{T_{cs}}; \frac{E_{ex}}{T_{cs}}; (B2)$$

where the ratio  $T_c=T_{cs}$  originates from  $!_n = T_{cs}$  with  $!_n$   $T_c$  as the characteristic energy scale in the bilayer.

If condition (B2) is satis ed, then the SMA is valid and  $T_{\rm c}$  is determ ined by the equations

$$\ln \frac{T_{cs}}{T_c} = \frac{1}{2} + \frac{2}{2} \frac{T_{cs}}{T_c} = \frac{1}{2} ; \quad (B3)$$

$$\tan \frac{a_s}{s} = -: \qquad (B4)$$

These equations can be further  $\sin pli$  ed in two  $\lim -$  iting cases which we consider below .

(1)  $\frac{d_s}{b_s}$  1:

in this case Eq. (B4) yields  $^{2} = -\frac{s}{b} \frac{s}{d_{s}}$ , and Eq. (B3) takes the form

$$\ln \frac{T_{cs}}{T_c} = \frac{1}{2} + \frac{1}{2} \frac{s}{b} \frac{T_{cs}}{d_s} \frac{1}{T_c} = \frac{1}{2} ; \quad (B5)$$

which reproduces the  $_{b}$   $\beta_{f}$  j lim it of Eq. (A2).

(2) 
$$-\frac{a_s}{b_s}$$
 1

in this case Eq. (B4) yields  $\frac{d_s}{s} = \frac{1}{2}$ , and Eq. (B3) takes the form

$$\ln \frac{T_{cs}}{T_c} = \frac{1}{2} + \frac{2}{8} \frac{s}{d_s} \frac{2}{T_{cs}} \frac{1}{2} : (B 6)$$

Equations (B3) { (B6) can be used for calculating the critical temperature  $T_{\rm c}$  and the critical thickness of the S layer  $d_{\rm s}^{\rm (cr)}$  below which the superconductivity in the SF bilayer vanishes (i.e.,  $T_{\rm c}=$  0).

### 1. Results for the critical tem perature

In the limit when  $T_{\rm c}$  is close to  $T_{\rm cs}$  , Eqs. (B5),(B6) yield

$$T_{c} = T_{cs} \quad 1 \quad \frac{2}{4} - \frac{s}{b} \frac{s}{d_{s}} \qquad \text{if} - m \text{ in } \frac{d_{s}}{s}; \frac{s}{d_{s}}; (B.7)$$

and

...

$$T_{c} = T_{cs} \ 1 \ \frac{2}{4} \frac{s}{d_{s}}^{2^{\#}} \quad \text{if} \frac{d_{s}}{s} \quad \text{max } 1; \frac{b}{s} :$$
(B8)

п

U sing relations (A 6) one can check that result (B 7) is equivalent to Eq. (A 7).

### 2. Results for the critical thickness

The critical thickness of the S layer d<sup>(cr)</sup> is de ned as the thickness below which there is no superconductivity in the SF bilayer:  $T_{c}(d_{s}^{(cr)}) = 0$ . When  $T_{c}$  ! 0, Eq. (B3) yields  $= 1 = \frac{P}{2} \frac{1}{E}$  (where E 1:78 is Euler's constant), and Eq. (B4) takes the form

$$\frac{1}{p \cdot \frac{1}{2_{E}}} \tan \frac{p \cdot \frac{1}{2_{E}}}{\frac{1}{2_{E}}} \frac{d_{s}^{(cr)}}{s} = \frac{1}{b};$$
 (B 9)

Explicit results for d<sub>s</sub><sup>(cr)</sup> can be obtained in lim iting cases:

$$\frac{d_{s}^{(cr)}}{s} = 2_{E} - \frac{d_{s}}{b} = \frac{d_{s}}{b} = 1;$$
 (B10)

and

$$\frac{d_s^{(cr)}}{s} = \frac{\frac{\varepsilon}{2}}{2} \qquad \text{if } \frac{d_s}{bs} \qquad 1: \qquad (B11)$$

# APPENDIX C:SPATIAL DEPENDENCE OF THE ORDER PARAMETER

A coording to the self-consistency equation, in the S layer the order parameter F (x; = 0) is proportional to (x):

$$F_{s}(x; = 0) = \frac{(x)}{(C1)};$$
 (C1)

where is the pairing constant which can be expressed via the D ebye energy:

$$1 = \ln \frac{2_{E}!_{D}}{T_{CS}}$$
 : (C2)

The pairing potential (x) can be found as the eigenvector of the matrix  $\hat{L}$   $\hat{1} \ln (T_{cs}=T_c)$  [see Eq. (33)], corresponding to the zero eigenvalue.

A fler that we can express F (x; = 0) in the F layer via (x) in the superconductor. The G reen function  $F_{f}(x;!_{n})$  in the F layer is given by Eq. (7), with C  $(!_{n})$  found from the boundary conditions:

$$C(!_{n}) = \frac{B_{f}}{b + B_{f}} \frac{F_{s}(0;!_{n})}{\cosh(k_{f}d_{f})}:$$
(C3)

The G reen function at the S side of the SF interface is

$$F_{s}(0;!_{n}) = \frac{F_{s}^{+}(0;!_{n}) + F_{s}(0;!_{n})}{2}; \quad (C4)$$

The sym m etric part  $F_{\rm s}^{\, +}\,$  is given by Eq. (31). The antisym m etric part is

 $F_{s} = C (!_{n}) \cosh(k_{s} [x d_{s}]);$  (C5)

with C  $(!_n)$  found from the boundary conditions:

$$C (!_{n}) = \frac{i \operatorname{Im} B_{f}}{A_{s}j_{b} + B_{f}j^{2} + (_{b} + \operatorname{ReB}_{f})} \frac{F_{s}^{+}(0;!_{n})}{\cosh(k_{s}d_{s})};$$
(C 6)

F in ally, the order parameter in the F layer is the Fourier transform [see Eq. (34)] of

$$F_{f}(x;!_{n}) = 1 + \frac{i \operatorname{Im} B_{f}}{A_{s}j_{b} + B_{f}f + (b + \operatorname{ReB}_{f})}$$

$$\frac{B_{f}}{b + B_{f}} \frac{\cosh(k_{f}[x + d_{f}])}{\cosh(k_{f}d_{f})} \int_{0}^{Z_{d_{s}}} G(0;y;!_{n})(y)dy:$$
(C7)

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